



Shirpur Education Society's
R. C. PATEL INSTITUTE OF TECHNOLOGY, SHIRPUR

An Autonomous Institute

(Affiliated to Dr. Babasaheb Ambedkar Technological University, Lonere)

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Programme: B.Tech in Electronics & Telecommunication Engineering

Year: II/Semester III (Exam Year: 2024-2025)

Subject: Electronics Devices & Circuits

Time: 09:00 am - 11:00 am (02:00 Hrs.)

Date: 09 Dec 2024

Max Marks: 60

END SEMESTER EXAMINATION ODD SEM -III (2024-2025)REGULAR

- Instructions:**
1. This question paper contains 2 pages
 2. Answer to each new question to be started on a fresh page.
 3. Figure in right hand side indicates full marks
 4. Draw neat diagrams wherever required.
 5. Assume suitable data if required.

1.

A. For the biasing circuit shown in fig.1.b Determine the IC, VCE, VC, VB and VE.
Transistor parameters are: VBE=0.7V, and $\beta=120$.

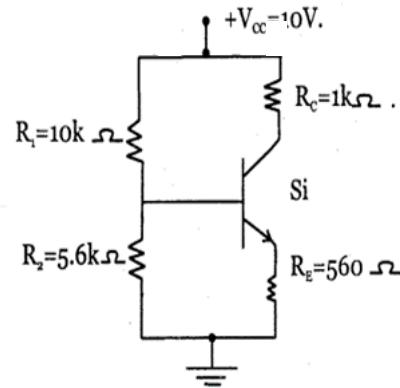


fig.1.b

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B. .

i. What is biasing? Why there is a need of biasing? Also explain what are the factors affecting stability of the transistor.

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----- OR -----

ii. For a voltage divider biasing circuit, $\beta = 100$, $R_B=370K$ and $R_E=2K$. Determine the stability Factor.

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2.

A. Draw and explain high frequency model for BJT in CE configuration.

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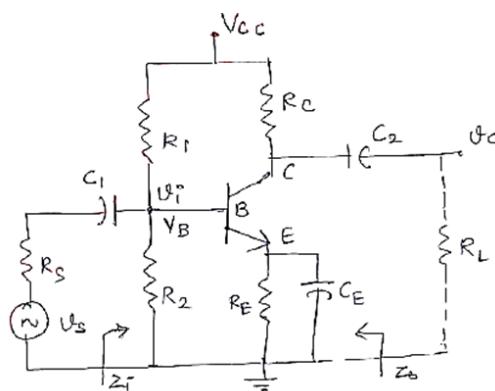
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B. .

i. Draw a small signal equivalent circuit of the given circuit in fig. and derive the expression for voltage gain, input impedance and output impedance.

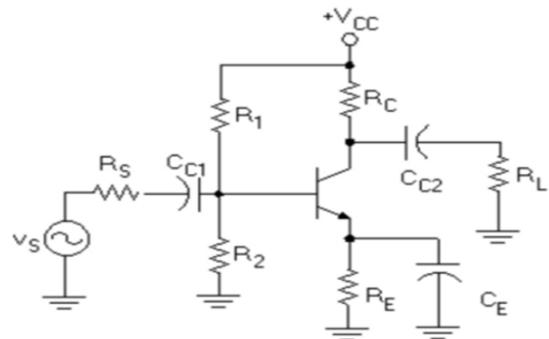
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----- OR -----

- ii. Derive the equation for Lower cutoff frequency f_L due to coupling capacitors and bypass capacitors for the CE amplifier circuit shown below. also find expression for midband voltage gain.



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3.

- A. What are the various topologies of negative feedback amplifiers? Discuss any one in detail.

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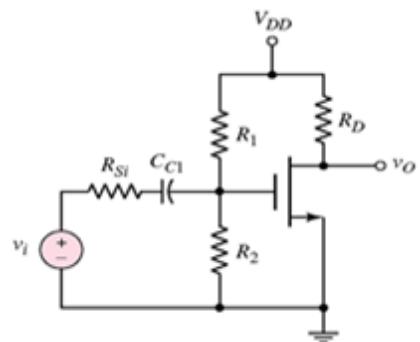
B. .

- i. Draw and explain the construction and working of N-Channel Depletion type MOSFET in detail with transfer and drain current characteristics.

----- OR -----

- ii. For the MOSFET common source amplifier shown in fig. below, analyze and derive the expression for voltage gain and input impedance.

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4.

- A. Draw and explain Hartley oscillator using BJT.

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B. .

- i. Derive an expression for maximum power efficiency of a Class B Push pull Power amplifier.

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----- OR -----

- ii. Differentiate between Voltage amplifier and power amplifier.

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